BGA461

Silicon Germanium GPS Low Noise Amplifier

RF & Protection Devices



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BGA461

Revision History: 2009-01-22, Rev.1.1 (Preliminary Data Sheet)

| Previous Version: 2008-06-27, Rev.1.0 | (Target Data Sheet) |
|---------------------------------------|---------------------|
|---------------------------------------|---------------------|

| Subjects (major changes since last revision) | | | | |
|--|--|--|--|--|
| | | | | |
| Marking code defined: BU | | | | |
| Thermal resistance and maximum rating for total power dissipation corrected | | | | |
| Typical values for insertion power gain, noise figure and input return loss adjusted, IIP3 specified | | | | |
| | | | | |
| - | | | | |



Silicon Germanium GPS Low Noise Amplifier

1 Silicon Germanium GPS Low Noise Amplifier

Features

Optimized for 1575 MHz Operation

High gain: 19.5 dB

Low Noise Figure: 1.1 dB

Supply voltage: 2.4 V to 3.2 V

4mA current consumption

Power off function

1 kV HBM ESD protection at all pins

B7HFM Silicon Germanium technology

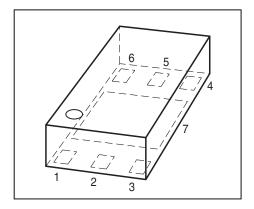
• RF output internally matched to 50 Ω

· Low external component count

Tiny TSLP-7-4 leadless package

Moisture sensitivity level: MSL 1

• Pb-free (RoHS compliant) package



TSLP-7-4



Application

• 1575 MHz GPS, Galileo, GPS phone

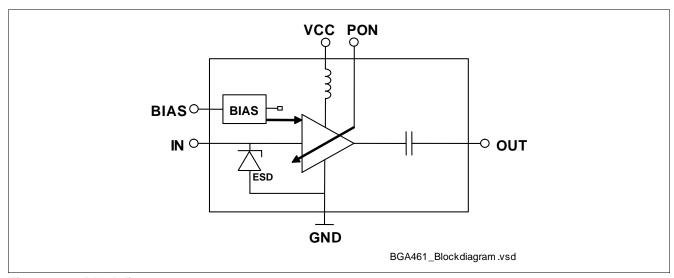


Figure 1 Blockdiagram

2 Description

The BGA461 is a front-end low noise amplifier for Global Positioning System (GPS) applications. The LNA provides 19.5 dB gain and 1.1 dB noise figure at a current consumption of 4 mA in the application configuration described in **Chapter 4**. The BGA461 is based upon Infineon Technologies' B7HFM Silicon Germanium technology. It operates over a 2.4 V to 3.2 V supply range.



Description

| Туре | Package | Marking |
|--------|----------|---------|
| BGA461 | TSLP-7-4 | BU |

Pin Definition and Function

Table 1 Pin Definition and Function

| Pin No. | Symbol | Function | | | |
|---------|--------|------------------|--|--|--|
| 1 | IN | LNA RF input | | | |
| 2 | BIAS | DC bias | | | |
| 3 | n.c. | not used | | | |
| 4 | PON | Power on control | | | |
| 5 | VCC | DC Supply | | | |
| 6 | OUT | LNA RF output | | | |
| 7 | GND | DC & RF ground | | | |

Maximum Ratings

Table 2 Maximum Ratings

| Parameter ¹⁾ | Symbol | Value | Unit |
|---|--------------|----------------------------|------|
| Voltage at pin VCC | $V_{\sf CC}$ | -0.3 3.6 | V |
| Voltage at pin IN | V_{IN} | -0.3 0.9 | V |
| Voltage at pin BIAS | V_{BIAS} | -0.3 0.9 | V |
| Voltage at pin OUT | V_{OUT} | -0.3 V _{CC} + 0.3 | V |
| Voltage at pin PON | V_{PON} | -0.3 V _{CC} + 0.3 | V |
| Current into pin VCC | I_{CC} | 10 | mA |
| RF input power | P_{IN} | 10 | dBm |
| Total power dissipation, $T_{\rm S}$ < 139 °C ²⁾ | P_{tot} | 90 | mW |
| Junction temperature | T_{J} | 150 | °C |
| Ambient temperature range | T_{A} | -30 85 | °C |
| Storage temperature range | T_{STG} | -65 150 | °C |
| ESD capability all pins (HBM: JESD22A-114) | V_{ESD} | 1000 | V |

¹⁾ All voltages refer to GND-Node.

Thermal resistance

Table 3 Thermal resistance

| Parameter | Symbol | Value | Unit |
|--|------------|-------|------|
| Junction - soldering point ¹⁾ | R_{thJS} | 125 | K/W |

¹⁾ For calculation of R_{thJA} please refer to Application Note Thermal Resistance

²⁾ $T_{\rm S}$ is measured on the ground lead at the soldering point



Electrical Characteristics

3 Electrical Characteristics

Table 4 Electrical Characteristics¹⁾: T_A = 25 °C, V_{CC} = 2.8 V, $V_{PON,ON}$ = 2.8 V, $V_{PON,OFF}$ = 0 V, f = 1575 MHz

| Parameter | Symbol | | Values | | | Note / Test Condition |
|--|-------------------|------|--------|------|-----|--|
| | | Min. | Тур. | Max. | | |
| Supply voltage | $V_{\sf CC}$ | 2.4 | 2.8 | 3.2 | V | |
| Supply current | $I_{\rm CC}$ | - | 4.0 | - | mA | ON-mode |
| | | - | 0.2 | 3 | μΑ | OFF-mode |
| Gain switch control voltage | V_{pon} | 1.5 | - | 3.2 | V | ON-mode |
| | | 0 | - | 0.5 | V | OFF-mode |
| Gain switch control current | I_{pon} | - | 1.5 | 3 | μΑ | ON-mode |
| | | - | 0 | 1 | μΑ | OFF-mode |
| Insertion power gain | $ S_{21} ^2$ | - | 19.5 | - | dB | High-gain Mode |
| Noise figure ²⁾ | NF | - | 1.1 | - | dB | $Z_{\rm S}$ = 50 Ω |
| Input return loss | RL_{in} | - | 11 | - | dB | |
| Output return loss | RL_{out} | - | >12 | - | dB | |
| Reverse isolation | $1/ S_{12} ^2$ | - | 35 | - | dB | |
| Power gain settling time ³⁾ | t_{S} | - | 20 | - | μs | OFF- to ON-mode |
| | | - | 50 | - | μs | ON- to OFF-mode |
| Inband input 3rd order intercept point ⁴⁾ | IIP_3 | - | -11 | - | dBm | f_1 = 1575 MHz f_2 = f_1 +/-1 MHz |
| Inband input 1 dB compression point | IP _{1dB} | - | -14 | - | dBm | |
| Stability | k | - | > 1.5 | - | | f = 20 MHz 10 GHz |

¹⁾ Measured on BGA461 application board described in **Chapter 4**, including PCB losses (unless noted otherwise)

²⁾ PCB tranmission line- and connector losses subtracted

³⁾ To within 1 dB of the final gain OFF- to ON-mode; to within 3 dB of the final gain ON- to OFF-mode

⁴⁾ Input Power = -40 dBm for each tone



Application Information

4 Application Information

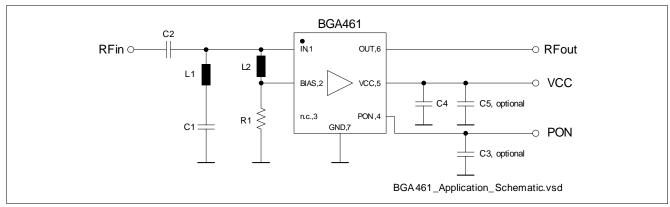


Figure 2 Application Schematic BGA461

Table 5 Bill of Materials

| | ora.o | | | | | | |
|------|-------------------------|----------|--------------|--------------------------------------|--|--|--|
| Name | Value | Package | Manufacturer | Function | | | |
| C1 | 10 nF | 0402 | Various | LF trap | | | |
| C2 | 2.7 pF | 0402 | Various | DC block and input matching | | | |
| C3 | 10 pF | 0402 | Various | (optional) Control voltage filtering | | | |
| C4 | 100 pF | 0402 | Various | Supply filtering | | | |
| C5 | 2.2 nF | 0402 | Various | (optional) Supply filtering | | | |
| L1 | 2.2 nH LQG15H series | 0402 | Murata | LF trap & input matching | | | |
| L2 | 33 nH LQG15H series | 0402 | Murata | Biasing | | | |
| R1 | 4.7 kΩ | 0402 | Various | Current adjustment | | | |
| N1 | BGA461 | TSLP-7-4 | Infineon | SiGe LNA | | | |

A list of all application notes is available at http://www.infineon.com/cms/en/product.



Package Information

5 Package Information

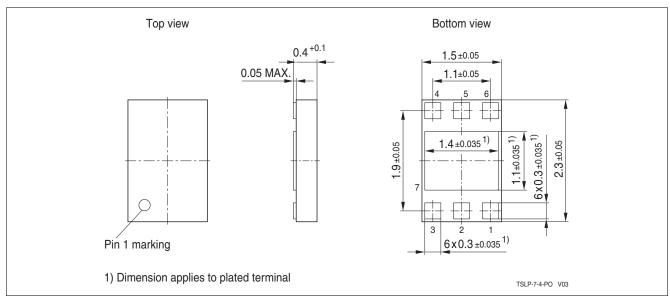


Figure 3 Package Dimensions for TSLP-7-4 (top, side and bottom view)

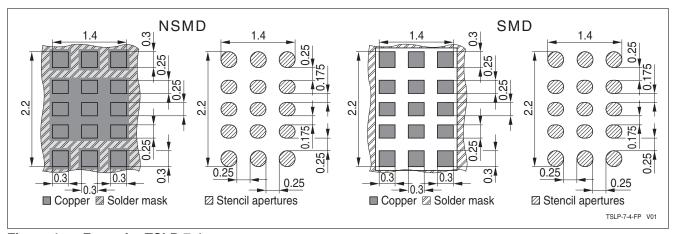


Figure 4 Footprint TSLP-7-4

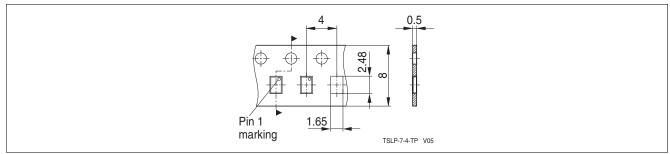


Figure 5 Tape & Reel Dimensions (Ø reel 330, pieces/reel 7500)

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